

Dual N-channel Power MOSFET: 12V, 1.3mohm, 37.3A

Product Summary

VSSS	VGSS	RSS(ON) TYP/MAX	IS MAX
12V	± 8V	1.00/1.30 mΩ@VGS=4.5V 1.10/1.45 mΩ@VGS=3.8V 1.25/2.00 mΩ@VGS=3.1V 1.60/3.20 mΩ@VGS=2.5V	37.3A

Marking Symbol Code

❖ Laser Marking Device Code: I



GS : Gostone
I : Marking Device Code
G : Factory Code
Y : Year Code
W : Week Code
L : LOT Code
O: Pin#1 Identifier

Form

❖ Tape & Reel Embossed Type: 5,000pcs / reel

Absolute Maximum Rating (Ta=25°C)

Parameter	Symbol	Rating	Unit
Source to Source Voltage	VSS	12	V
Gate to Source Voltage	VGS	±8	V
Source Current	DC IS1 *1	18.7	A
	DC IS2 *2	37.3	A
	Pulse ISP *2*3	149	A
Total Dissipation	DC PD1 *1	0.48	W
	DC PD2 *2	1.92	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Thermal Characteristic (Ta=25°C)

Parameter	Symbol	Rating	Unit
Thermal Resistance	Rth *1	260	°C/W
	Rth *2	65	°C/W

Note *1 Mounted on FR4 board (25.4mm x 25.4mm x t1.0mm)

with minimum copper pad (50.6mm², 36μm thickness copper)

Note *2 Mounted on FR4 board (25.4mm x 25.4mm x t1.0mm)

with maximum copper pad (618.4mm², 36μm thickness copper)

Note *3 t=10μs, duty cycle ≤ 1%

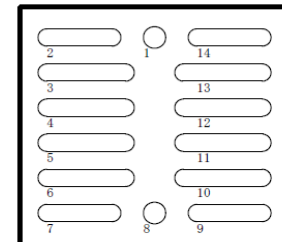
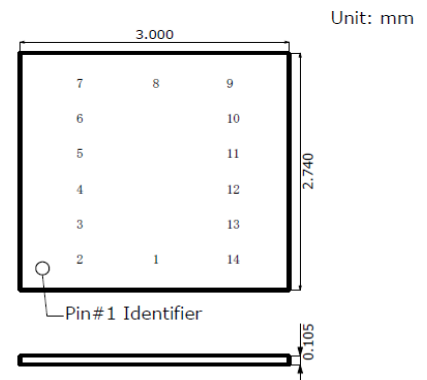
Features

- ❖ CSP (Chip Size Package)
- ❖ Halogen-Free / RoHS Compliant
- ❖ 2.5V Drive Low Source-Source On-State Resistance
- ❖ Gate Resistor Installed Common-Drain Type MOSFET
- ❖ ESD Protection Diode Installed (Gate-Source)

Application

- ❖ Lithium-Ion Secondary Battery Protection Circuits

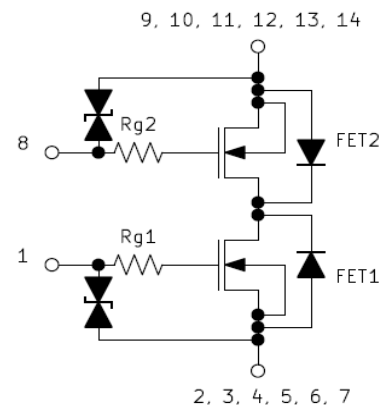
Pin Assignment



FET1: 2,3,4,5,6,7: Source1, 1: Gate1

FET2: 9,10,11,12,13,14: Source2, 8: Gate2

Equivalent circuit

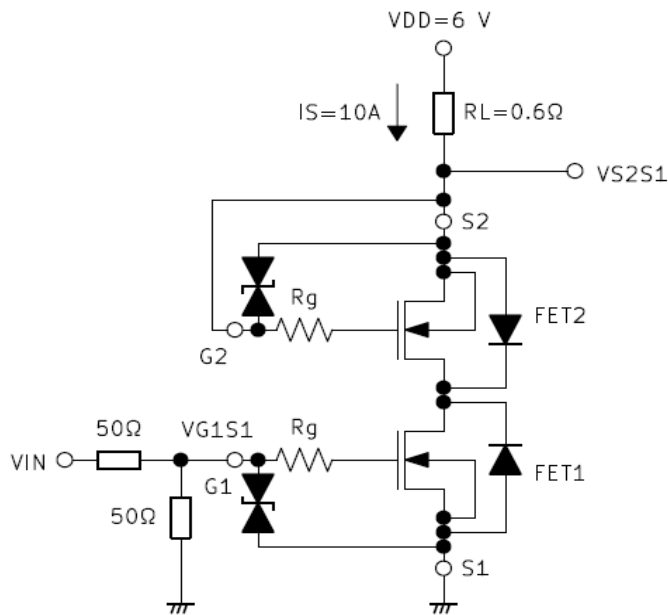


Electrical characteristics (Ta=25°C ± 3°C)

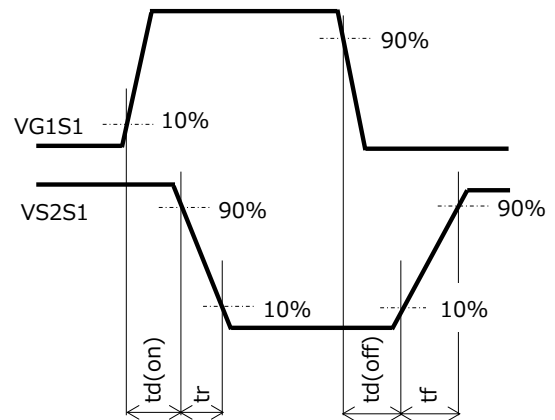
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-Source Breakdown Voltage	VSSS	IS=1mA, VGS=0V	12.0			V
Zero Gate Voltage Source Current	ISSS	VSS=12V, VGS=0V			1.0	μA
Gate-Source Leakage Current	IGSS1 IGSS2	VGS=±8V, VSS=0V VGS=±5V, VSS=0V			±10 ±1.0	μA
Gate-Source Threshold Voltage	Vth	VSS=6.0V, IS=1.0mA	0.4	0.9	1.4	V
Source-Source On-State Resistance	RSS(on)1 RSS(on)2 RSS(on)3 RSS(on)4	IS=10A, VGS=4.5V IS=10A, VGS=3.8V IS=10A, VGS=3.1V IS=10A, VGS=2.5V	0.70 0.75 0.80 0.90	1.00 1.10 1.25 1.60	1.30 1.45 2.00 3.20	mΩ
Body Diode Forward Voltage	VF(S-S)	IF=10A, VGS=0V		0.7	1.2	V
Input Capacitance *1	Ciss	VSS=10V, VGS=0V, f=1kHz		6,540		pF
Output Capacitance *1	Coss			975		
Reverse Transfer Capacitance *1	Crss			945		
Turn-On Delay Time *1 *2	td(on)	VDD=6V, VGS=0 to 4.0V, IS=10A		1.7		μs
Rise Time *1 *2	tr			5.2		
Turn-Off Delay Time *1 *2	td(off)	VDD=6V, VGS=4.0 to 0V, IS=10A		4.2		μs
Fall Time *1 *2	tf			7.4		
Total Gate Charge *1	Qg	VDD=6V, VGS=0 to 4.0V, IS=20A		75		nC
Gate-Source Charge *1	Qgs			12		
Gate-Drain Charge *1	Qgd			26		
Gate Resistance *1	Rg	f=1MHz		570		Ω

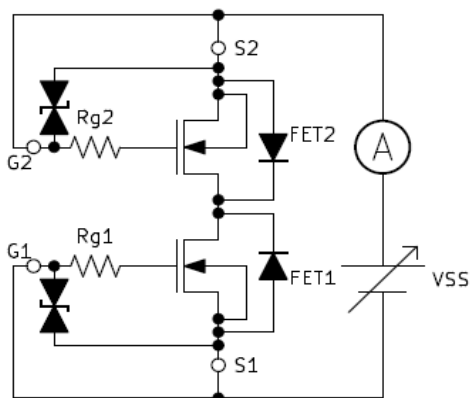
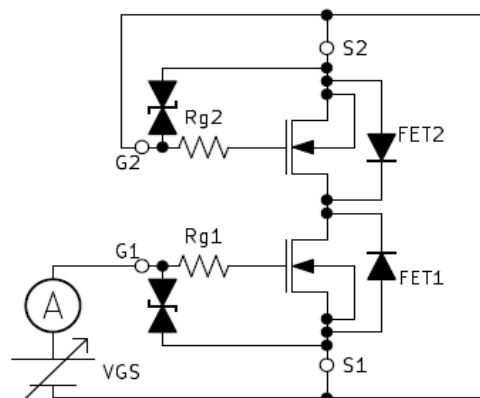
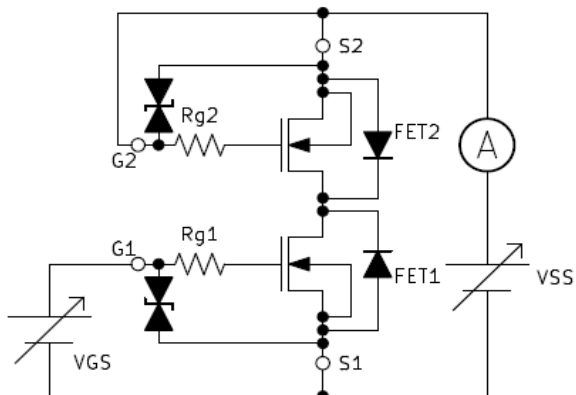
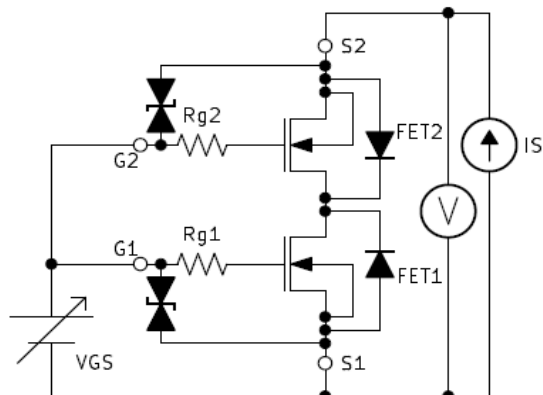
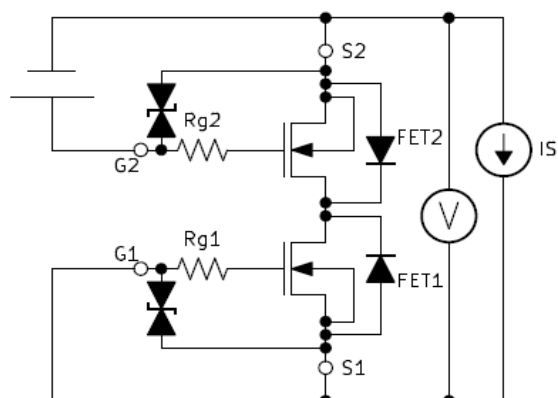
Note *1 Guaranteed by Design

Note *2 Measurement Circuit for Switching Characteristics

FET1 Measurement Circuit for Switching Characteristics td(on), tr, td(off), tf
FET2: Gate-Source Short


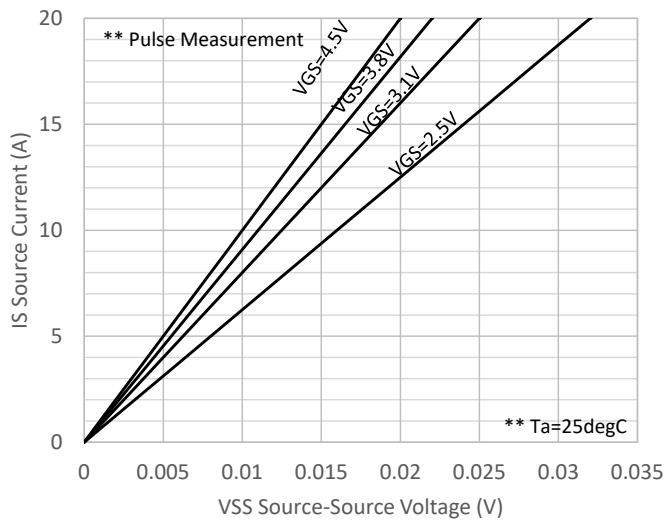
(Definition of Switching Measurement Detection)



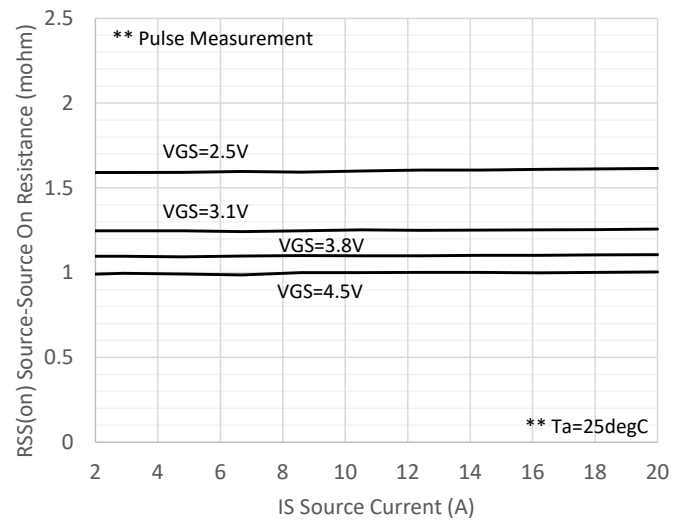
Test Circuit for FET1
**Test Circuit 1
VGSS/ISS**

**Test Circuit 2
IGSS/1/2**

**Test Circuit 3
 V_{th}**

**Test Circuit 4
RSS(on)**

**Test Circuit 5
VF(S-S)**




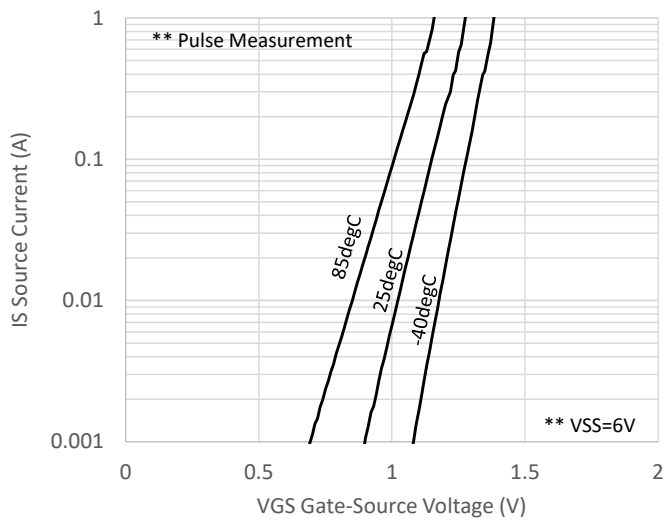
IS to VSS



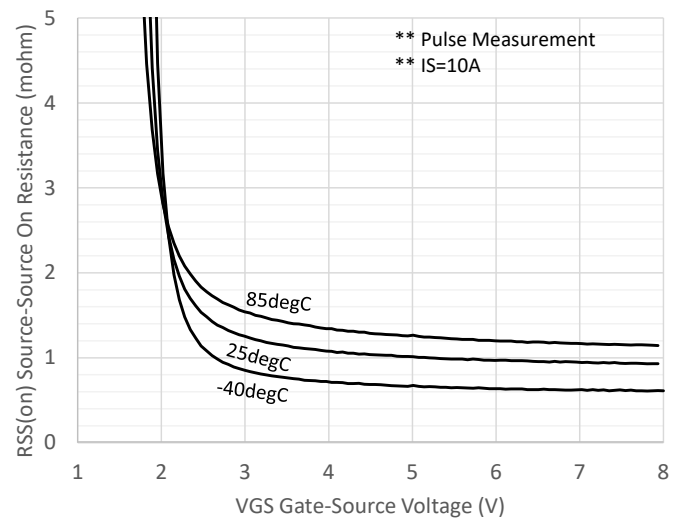
RSS(on) to IS



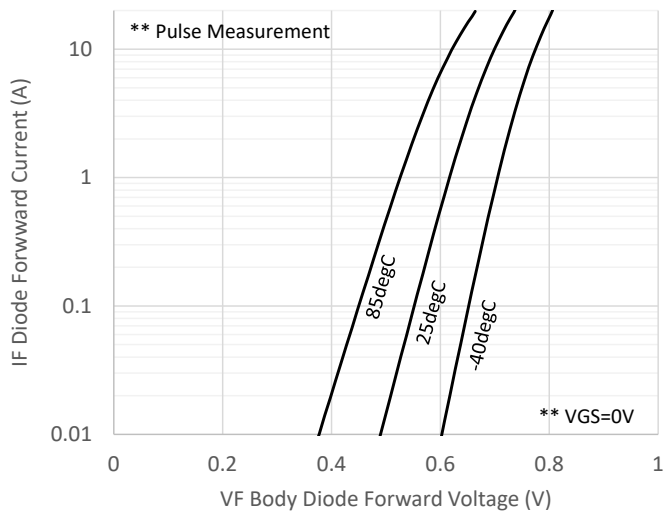
IS to VGS



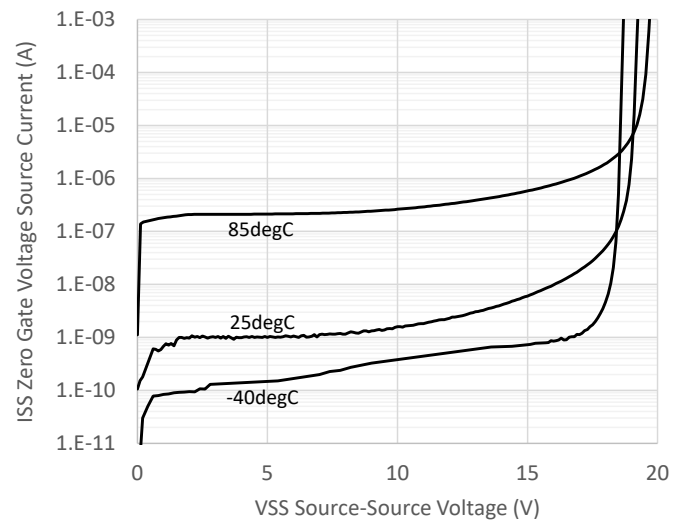
RSS(on) to VGS



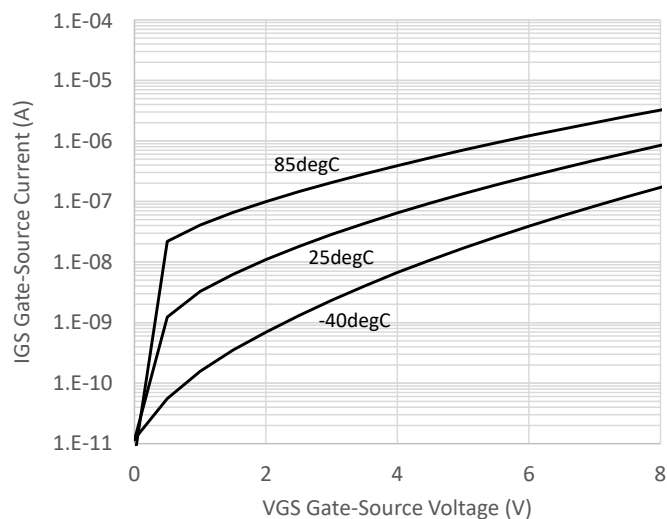
IF to VF



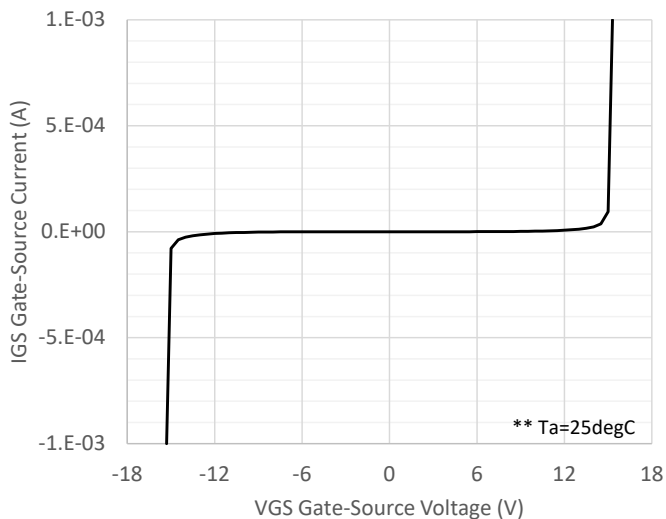
ISS to VSS



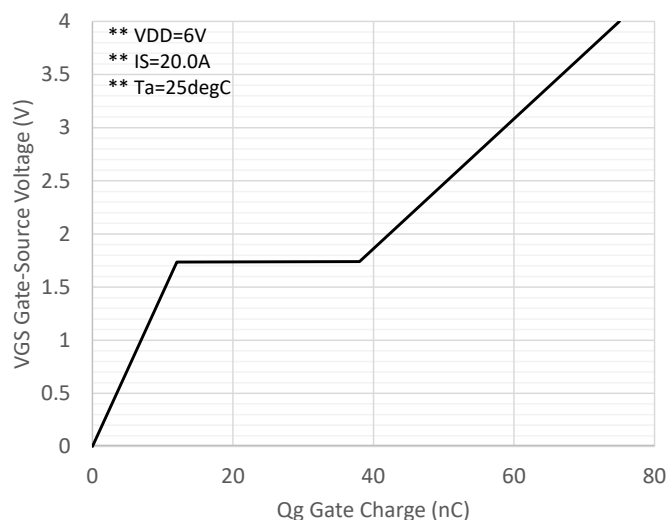
IGS to VGS



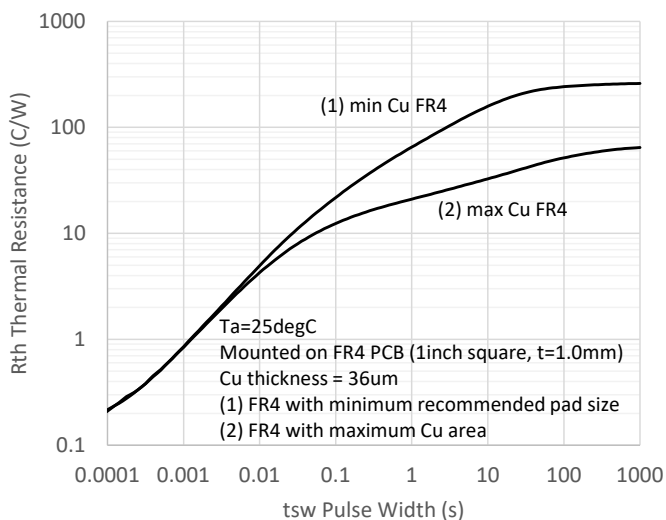
IGS to VGS



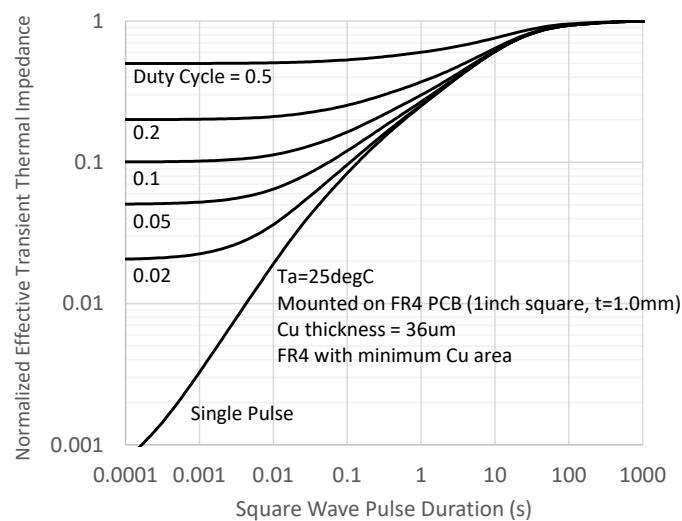
Dynamic Input / Output Characteristics



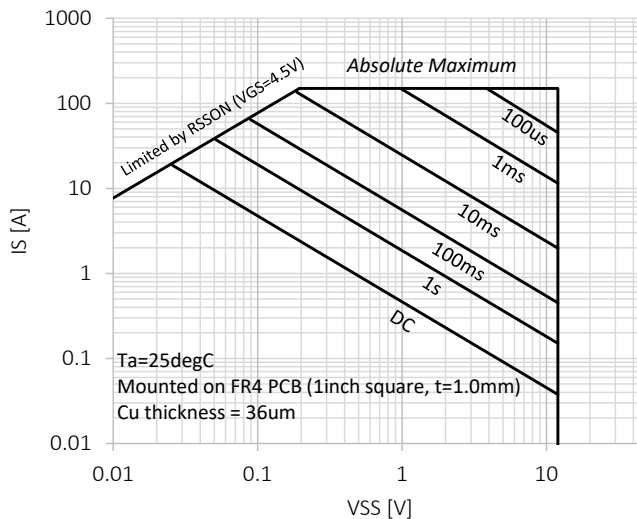
Rth to tsw



Thermal Response



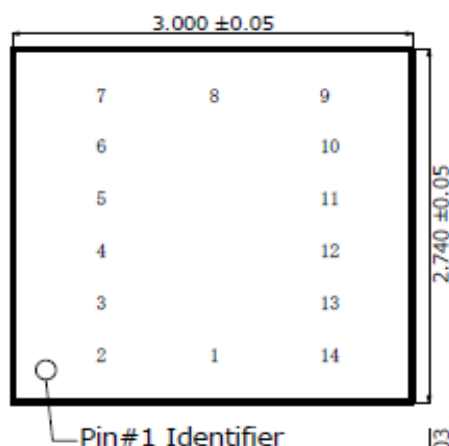
Safe Operating Area



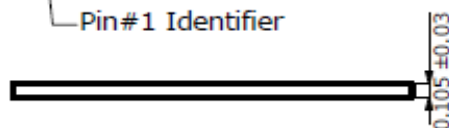
Package outline dimensions

Unit: mm

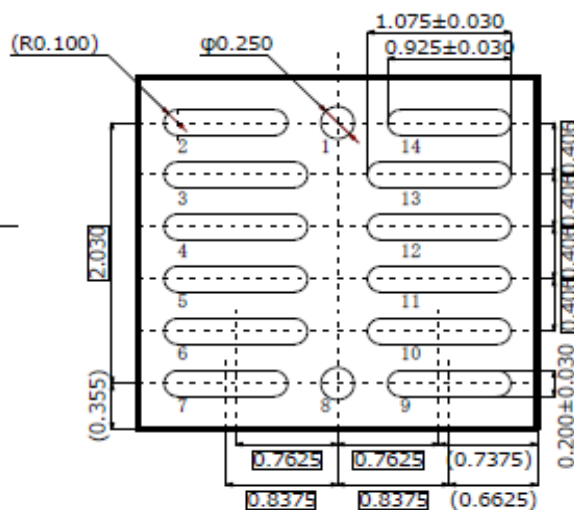
Top View



Front View



Bottom View

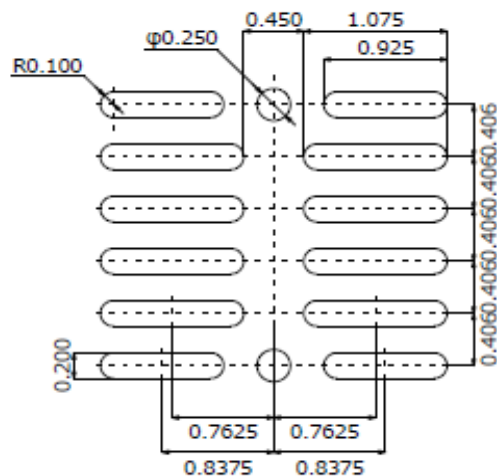
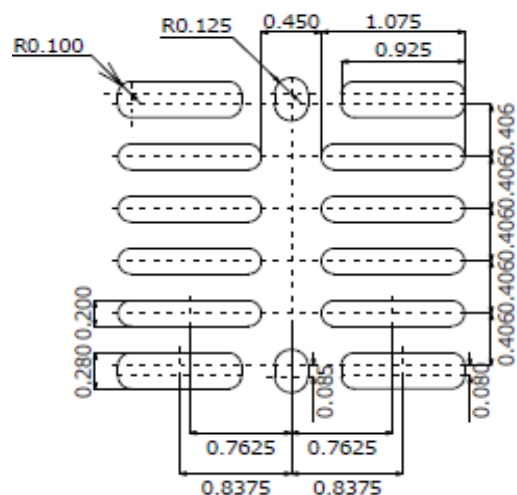


(Reference) Board Land Pattern

(Reference) Stencil Mask Pattern

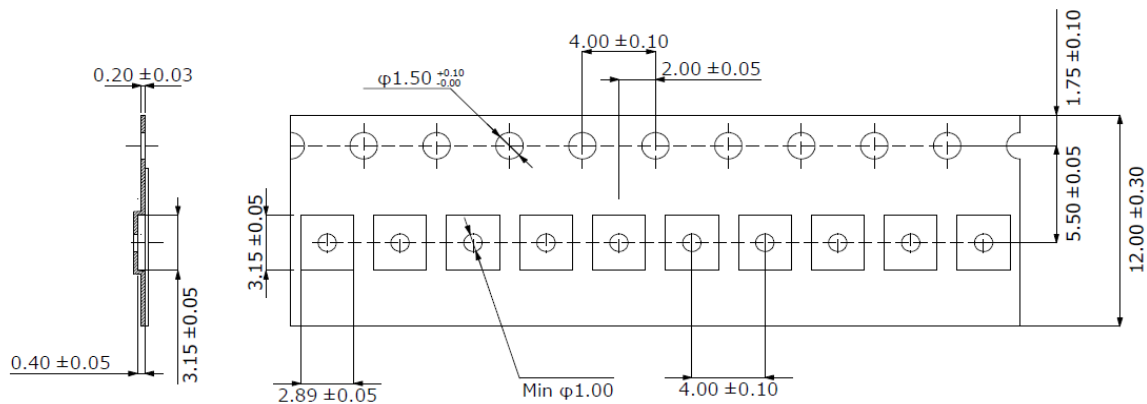
Unit: mm

Unit: mm

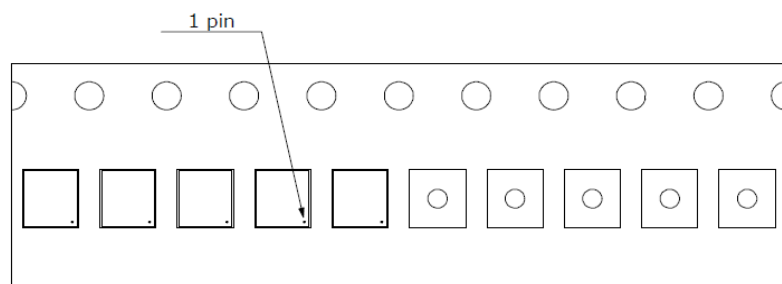


Form

Tape & Reel Embossed Type: 8,000pcs / reel
 Factory PKG Code: WLCSP3.00x2.74_14
 Tape Width: 12mm, Pitch: 4mm, Reel Size:
 7inch



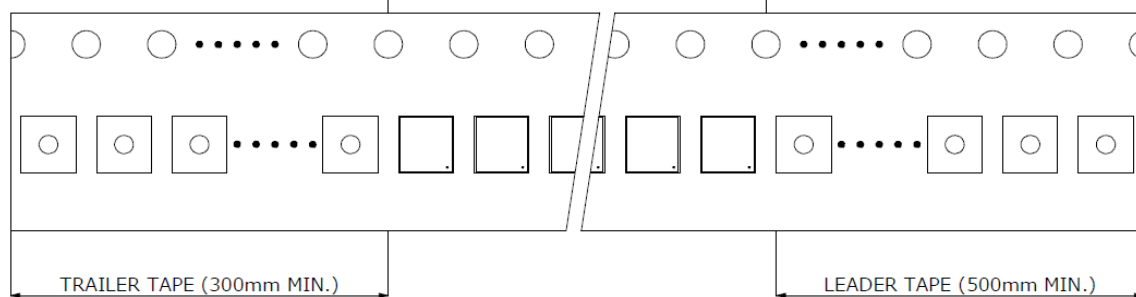
1pin Direction



Tape end

COMPONENTS TAPE (ORIENTATION IN POCKET)

Leader part



Feeding Direction

Important Notice

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